

Critical Organics Risk Assessment of High-Purity Polymer Piping

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This type of study can not be done alone!



IRDS Critical Components Task Force IRDS UPW Task Force UNISERS SCREEN Asahi America **Daiken America** Entegris **Georg Fischer** Saint Gobain Solvay



Presentation Outline

- Introduction and Problem Statement
- Technical Objectives
- Analytical Metrologies
- Test Results
 - PFA and PVDF Extract Analysis
 - Wafer Surface Analysis
 - Thermal/Vacuum Desorption Analysis
- Summary and Take-aways



Introduction and Problem Statement

- Organic contamination present in UPW pose a risk of depositing on the wafer surface during processing and cleaning. Of greatest concern are those deposits that are non-volatile critical organics.
- Pressure for increased yield, improved performance and long-term reliability combined with the lack of online metrology require that critical organic contamination be proactively managed.
- New tools and methods are needed to better understand these risks and support material improvements and new material development.



Source: 2021 IRDS UPW Particle Precursor (HMWO) Deposition Study - UNISER



Technical Objectives

- 1. To quantify critical organic extracted from high-purity piping by hot UPW; specifically, PFA and PVDF.
- 2. Assess the affinity of the organic contaminants to the wafer surface during spin processing.
- 3. Determine the relative concentrations of organic contamination remaining on the wafer surface as a function of temperature.



Molecular Finger Printing



Analytical Metrologies



Nanoparticle Sizing (LNS)

Surface Enhanced Particle Sizing (SEPS)

Surface Enhanced Raman Spectroscopy (SERS)



Phase 1 Proof of Concept Test Approach















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- Particle precursors are evident in both extracts. PVDF may have a higher ratio of particle precursor to native particles.
- Good signal to noise between extracts and method blank.



Total Organic Carbon Comparison

Surface Normalized LNS Particle Concentration vs TOC



PVDF particle and particle precursors appear to be more susceptible to oxidation by UV than those in the PFA extract.*

* This may be related to differences in the ratio of particle precursor and native particles between PFA and PVDF extract. More study is need here.



Wafer Prep and Surface Particle Analysis



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1 cm x 1 cm scan areas

Total Particle (8 -		Wafer Location					
Wafer	Preparation	540 nm)	1	2	3	4	5
1	None	36					
2	UPW	41					
3	Bottle Blank	55					
4	Method Blank (no dilution)	4270					
5	PVDF extract 100:1	306	80	68	115	1,165	100
6	PVDF extract 100:1	128	84	147	168	160	81
7	PVDF extract 10:1	12537	468	2,003	1,676	42,184	16,356
8	PVDF extract 10:1	16621	260	56,508	9,648	64	16,627
9	PFA extract 100:1	16897	3,296	55,724	10,584	3,296	11,585
10	PFA extract 100:1	10335	9,152	11,480	9,276	9,656	12,110
11	PFA extract 10:1	19548	1,456	11,044	51,576	336	33,328
12	PFA extract 10:1	13840	13,064	16,396	9,848	12,396	17,496
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Extremely high variability over the wafer surface.



Surface Enhanced Raman Summary

Mafar	Total Particle (8 -		Wafer Location					
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5	PVDF extract 100:1	306	80	68	115	1,165	100	
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However...it is clear that particles from PFA and PVDF extract adhere to the wafer surface!!



Wafer	Method blank (W4)	PVDF-extract 10:1 (W6)	PFA Extract 10:1 (W9)
Spectra acquired	21	51	62
Inorganic spectra	42.9%	8.3%	10.9%
Organic spectra with 5 of the reference bands	0.0%	6.3%	1.8%
Organic spectra with 4 of the reference bands	4.8%	25.0%	14.5%
Organic spectra with 3 of the reference bands	9.5%	56.3%	29.1%

Three or more reference peaks identified in spectra





Alternate Approach to Wafer Preparation – Sequential Spin Coating





Alternate Approach to Wafer Preparation – Sequential Spin Coating





Alternate Approach to Wafer Preparation – Sequential Spin Coating Different on-wafer PSD for PEA and PVDE











Future Approach to Wafer Preparation – Sequential Spin Coating





- Different on-wafer PSD for PFA and PVDF
- Linear increase in particle concentration with # of coats





Future Approach to Wafer Preparation – Sequential Spin Coating





- Different on wafer PSD for PFA and PVDF
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• Important to understand the reason for the intercept offset before we can use this as a proactive tool.



Candidate Approach to ID Critical Organics – Thermal and Vacuum Desorption by FTIR (PFA Example)



IR peak intensity decreases with extract evaporation; lower volatiles "critical organic" remain. Released PFA volatiles calculated by subtracting 72-hr. spectrum from 20 min spectrum.



Candidate Approach to ID Critical Organics – Thermal and Vacuum Desorption by FTIR (PVDF Example)



IR peak intensity decreases with extract evaporation; lower volatiles "critical organic" remain.

Released PVDF volatiles calculated by subtracting 1 Torr, 90°C spectrum from 10 Torr spectrum.



Summary and Take-aways

- Extended SEMI F40 extraction* of PFA tube and PVDF pipe provides an extract solution with particle and particle precursor concentrations suitable for quantification by LNS and TOC analysis.
- Particle and particle precursor extracts extracted by hot UPW adhere to the wafer surface under spin-coat processing as measured by Surface Enhanced Particle Sizing (SEPS) and Surface Enhanced Raman Spectroscopy (SERS) and therefore present a yield risk.
- Single, hand-pour deposition of the extract solution fails to provide a uniform distribution of particles over the surface.
- Sequential spin coating in conjunction with SEPS may have potential for quantifying particle adhesion risk with the particle concentration in the solution. Additional work is needed to validate repeatability and understand the reason for the intercept offset.
- FTIR with varied temperature and vacuum is showing promise in identifying desorbed and residual organics (i.e. critical organics).

*with concentrated surface to volume ratio



Thank you for your attention!!





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